Ms. Sumedha Gupta

Designation: Assistant Professor

Qualification: Ph.D (Purs.), M.Tech, B.Tech

Specialization: VLSI Design and Modeling of Microelectronic Devices

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Education

Ph.D. (Pursuing) from Delhi Technological University.

M.Tech in Signal Processing from GGSIPU, 2011-2013.

B. Tech in Electronics and Communication Engineering from GGSIPU, 2007-2011.

Research Interest

VLSI Design, Semiconductors, Modeling and Design

Publications

International Journals: 02 International Conferences: 02

List of Publications

- [1]. Gupta, S., Pandey, N., & Gupta, R. S. (2020, December). Investigation of dual-material double gate junctionless accumulation-mode cylindrical gate all around (dmdg-jlam-cgaa) mosfet with high-k gate stack for low power digital applications. In 2020 IEEE 17th India council international conference (INDICON) (pp. 1-4). IEEE.
- [2]. Gupta, S., Pandey, N., & Gupta, R. S. (2021). Analytical modeling of dual-metal gate stack engineered junctionless accumulation-mode cylindrical surrounding gate (DMGSE-JAM-CSG) MOSFET. *Applied Physics A*, 127(7), 1-10.
- [3]. Gupta, S., Pandey, N., & Gupta, R. S. (2021, May). Analog Performance of Dual-Metal Gate Stack Architecture of Junctionless Accumulation-Mode Cylindrical Surrounding Gate (DMGSA-JAM-CSG) MOSFET. In 2021 Devices for Integrated Circuit (DevIC) (pp. 1-5). IEEE.
- [4]. Gupta, S., Pandey, N., & Gupta, R. S. (2021). Temperature dependency and linearity assessment of dual-metal gate stack junctionless accumulation-mode cylindrical surrounding gate (DMGS-JAM-CSG) MOSFET. *Physica Scripta*, *96*(12), 124055.